

Q3-Class HiperFET™ **Power MOSFET**

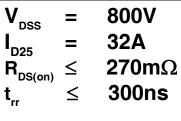
IXFK32N80Q3 IXFX32N80Q3

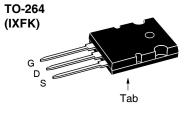
N-Channel Enhancement Mode Avalanche Rated Fast Intrinsic Rectifier

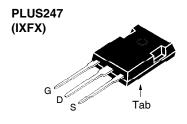


| Test Conditions | Maximum R | atings |
|---|--|--|
| T _J = 25°C to 150°C | 800 | V |
| $T_J = 25$ °C to 150°C, $R_{GS} = 1M\Omega$ | 800 | V |
| Continuous | ±30 | V |
| Transient | ±40 | V |
| T _C = 25°C | 32 | A |
| $T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$ | 80 | Α |
| T _C = 25°C | 32 | A |
| $T_{c} = 25^{\circ}C$ | 3 | J |
| $I_{_{S}} \le I_{_{DM}}, V_{_{DD}} \le V_{_{DSS}}, T_{_{J}} \le 150^{\circ}C$ | 50 | V/ns |
| T _c = 25°C | 1000 | W |
| | -55 +150 | °C |
| | 150 | °C |
| | -55 +150 | °C |
| Maximum Lead Temperature for Soldering | 300 | °C |
| Plastic Body for 10s | 260 | °C |
| Mounting Torque (TO-264) | 1.13/10 | Nm/lb.in |
| Mounting Force (PLUS247) | 20120 /4.527 | N/lb |
| TO-264 PLUS247 | 10 6 | g |
| | $\begin{split} &T_{_{\!J}}=25^{\circ}\text{C to }150^{\circ}\text{C}\\ &T_{_{\!J}}=25^{\circ}\text{C to }150^{\circ}\text{C}, R_{_{\!GS}}=1\text{M}\Omega\\ &\text{Continuous}\\ &\text{Transient}\\ &T_{_{\!C}}=25^{\circ}\text{C}\\ &T_{_{\!C}}=25^{\circ}\text{C}, \text{Pulse Width Limited by }T_{_{\!J\!M}}\\ &T_{_{\!C}}=25^{\circ}\text{C}\\ &T_{_{\!C}}=25^{\circ}\text{C}\\ &I_{_{\!S}}\leq I_{_{\!D\!M}}, V_{_{\!D\!D}}\leq V_{_{\!D\!S\!S}}, T_{_{\!J}}\leq 150^{\circ}\text{C}\\ &T_{_{\!C}}=25^{\circ}\text{C}\\ &I_{_{\!S}}\leq I_{_{\!D\!M}}, V_{_{\!D\!D}}\leq V_{_{\!D\!S\!S}}, T_{_{\!J}}\leq 150^{\circ}\text{C}\\ &T_{_{\!C}}=25^{\circ}\text{C}\\ &\text{Maximum Lead Temperature for Soldering Plastic Body for 10s}\\ &\text{Mounting Torque (TO-264)}\\ &\text{Mounting Force (PLUS247)} \end{split}$ | $\begin{array}{cccccccccccccccccccccccccccccccccccc$ |

| | R |
|-----|-----------------|
| D D | t _{rr} |







| G | = | Gate | D | = | Drain |
|---|---|--------|-----|---|-------|
| S | = | Source | Tab | = | Drain |

Features

- Low Intrinsic Gate Resistance
- Low Package Inductance
- Fast Intrinsic Rectifier
- Low R_{DS(on)} and Q_G

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode **Power Supplies**
- DC Choppers
- Temperature and Lighting Controls

| Symbol Test Conditions Charac | | | cteristic Values | | |
|-------------------------------|---|------|------------------|------|----|
| $(T_J = 25^{\circ}C)$ | Unless Otherwise Specified) | Min. | Тур. | Max. | |
| BV _{DSS} | $V_{GS} = 0V, I_{D} = 1mA$ | 800 | | | V |
| V _{GS(th)} | $V_{DS} = V_{GS}, I_{D} = 4mA$ | 3.0 | | 6.0 | V |
| I _{GSS} | $V_{GS} = \pm 30V, V_{DS} = 0V$ | | | ±200 | nA |
| I _{DSS} | $V_{DS} = 0.8 \cdot V_{DSS}, V_{GS} = 0V$ | | | | μА |
| | T _J = 125°C | | | 2 | mΑ |
| R _{DS(on)} | $V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$ | | | 270 | mΩ |



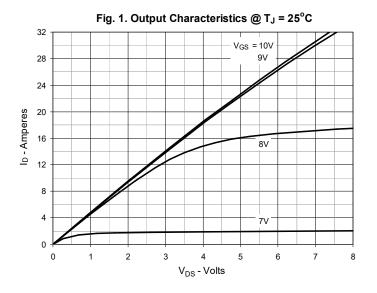
| Symbol Test Conditions Character (T ₁ = 25°C Unless Otherwise Specified) Min. | | | eteristic Values Typ. Max. | | |
|--|---|----|---------------------------------|------------|--|
| g_{fs} | $V_{DS} = 20V, I_{D} = 0.5 \cdot I_{D25}, \text{ Note 1}$ | 16 | 26 | S | |
| C _{iss} | | | 6940 | pF | |
| C _{oss} | $V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$ | | 700 | pF | |
| C_{rss} | | | 63 | pF | |
| R_{Gi} | Gate Input Resistance | | 0.16 | Ω | |
| t _{d(on)} | Resistive Switching Times | | 38 | ns | |
| t _r | $V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$ | | 13 | ns | |
| t _{d(off)} | | | 45 | ns | |
| t _f | $R_{_{\rm G}} = 1\Omega$ (External) | | 10 | ns | |
| Q _{g(on)} | | | 140 | nC | |
| Q _{gs} | $V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$ | | 48 | nC | |
| Q _{gd} | | | 63 | nC | |
| R _{thJC} | | | | 0.125 °C/W | |
| \mathbf{R}_{thCS} | | | 0.15 | °C/W | |

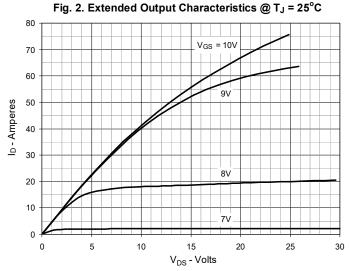
Source-Drain Diode

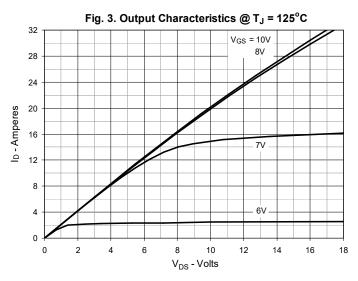
| Symbol Test Conditions C | | Chara | Characteristic Values | | | |
|---|---|-------|-----------------------|------|---------------|--|
| $(T_J = 25^{\circ}C)$ | Unless Otherwise Specified) | Min. | Тур. | Max. | | |
| I s | $V_{GS} = 0V$ | | | 32 | Α | |
| I _{SM} | Repetitive, Pulse Width Limited by $T_{_{JM}}$ | | | 128 | Α | |
| V _{sD} | $I_F = I_S$, $V_{GS} = 0V$, Note 1 | | | 1.4 | V | |
| t _{rr} Q _{RM} J _{RM} | $I_F = 16A$, $-di/dt = 100A/\mu s$ $V_R = 100V$, $V_{GS} = 0V$ | | 1.4 12.0 | 300 | ns μC Α | |

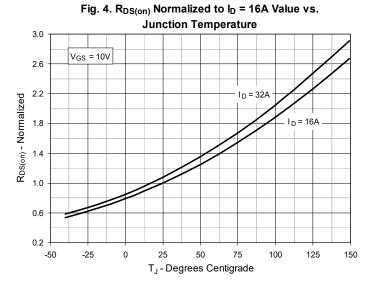
Note 1. Pulse test, $t \le 300 \mu s$, duty cycle, $d \le 2\%$.

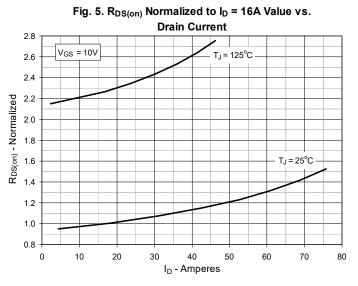


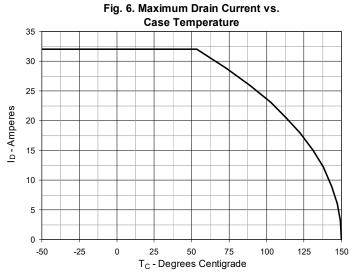




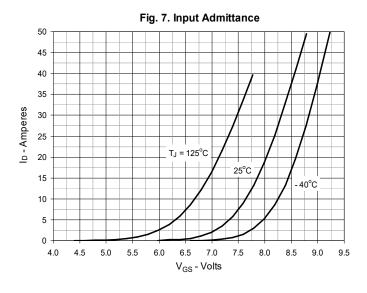


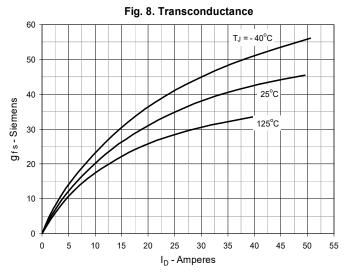


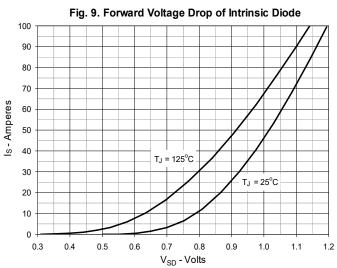


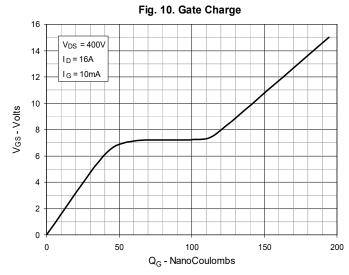


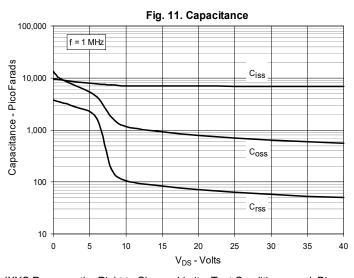


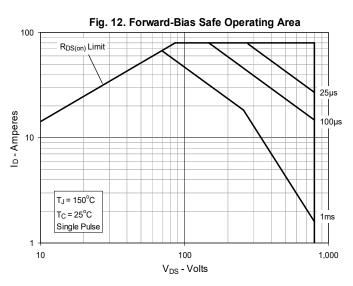












IXYS Reserves the Right to Change Limits, Test Conditions, $\,$ and $\,$ Dimensions.



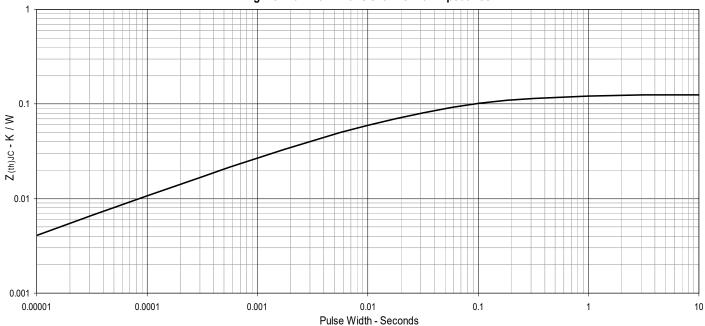
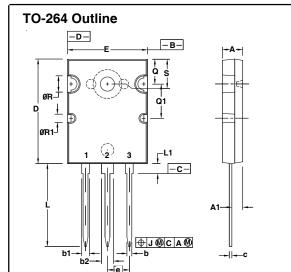


Fig. 13. Maximum Transient Thermal Impedance





BACK SIDE

_A _ ØP ⊕ ØK @ D B @

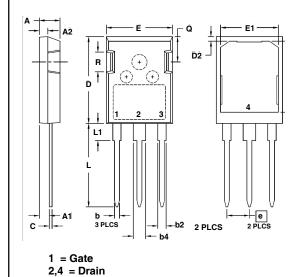
1 = Gate 2,4 = Drain

3 = Source

| SYMBOL | INCHES | | MILLIMETERS | |
|--------|---------|-------|-------------|-------|
| SIMBUL | MIN | MAX | MIN | MAX |
| Α | .185 | .209 | 4.70 | 5.31 |
| A1 | .102 | .118 | 2.59 | 3.00 |
| b | .037 | .055 | 0.94 | 1.40 |
| b1 | .087 | .102 | 2.21 | 2.59 |
| b2 | .110 | .126 | 2.79 | 3.20 |
| С | .017 | .029 | 0.43 | 0.74 |
| D | 1.007 | 1.047 | 25.58 | 26.59 |
| E | .760 | .799 | 19.30 | 20.29 |
| е | .215BSC | | 5.46 | BSC |
| J | .000 | .010 | 0.00 | 0.25 |
| K | .000 | .010 | 0.00 | 0.25 |
| L | .779 | .842 | 19.79 | 21.39 |
| L1 | .087 | .102 | 2.21 | 2.59 |
| ØΡ | .122 | .138 | 3.10 | 3.51 |
| Ø₽1 | .270 | .290 | 6.86 | 7.37 |
| Q | .240 | .256 | 6.10 | 6.50 |
| Q1 | .330 | .346 | 8.38 | 8.79 |
| ØR | .155 | .187 | 3.94 | 4.75 |
| ØR1 | .085 | .093 | 2.16 | 2.36 |
| S | .243 | .253 | 6.17 | 6.43 |

PLUS247™ Outline

3 = Source



| SYM | INCH | IES | MILLIN | 1ETERS |
|------|------|------|----------|--------|
| 2110 | MIN | MAX | MIN | MAX |
| Α | .190 | .205 | 4.83 | 5.21 |
| Α1 | .090 | .100 | 2.29 | 2.54 |
| A2 | .075 | .085 | 1.91 | 2.16 |
| b | .045 | .055 | 1.14 | 1,40 |
| b2 | .075 | .087 | 1.91 | 2.20 |
| b4 | .115 | .126 | 2.92 | 3,20 |
| С | .024 | 031، | 0.61 | 0,80 |
| D | .819 | .840 | 20.80 | 21.34 |
| D1 | .650 | .690 | 16.51 | 17.53 |
| D2 | .035 | .050 | 0.89 | 1.27 |
| E | .620 | .635 | 15.75 | 16.13 |
| E1 | .520 | .560 | 13.08 | 14.22 |
| е | .215 | BSC | 5.45 BSC | |
| L | .780 | .810 | 19.81 | 20.57 |
| L1 | .150 | .170 | 3.81 | 4.32 |
| Q | .220 | .244 | 5.59 | 6.20 |
| R | .170 | 190، | 4.32 | 4.83 |





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